NSN 5961-00-813-5971

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-813-5971 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.058 inches **Overall Diameter:** 0.122 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium **Voltage Rating In Volts Per Characteristic:** 100.0 forward voltage, average **Current Rating Per Characteristic:** 200.00 microamperes source cutoff current pascal **Capacitance Rating In Picofarads:** 0.5 **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Test Data Document:** 13499-353-3603 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No